NSN 5962-01-373-9120

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Display conso e/i fscm 49956
Features Provided:
Bipolar and electrically alterable and low power and programmed and high reliability
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Case Outline Source And Designator:
D-2 mil-m-38510
Current Rating Per Characteristic:
100.00 milliamperes average forward current averaged over a full 60-hz cycle not applicable
Terminal Surface Treatment:
Solder
Product Name:
1024-bit bipola (256x4) electrically programmable read only memory
Voltage Rating And Type Per Characteristic:
-0.5 volts applied and 7.0 volts applied
Memory Device Type:
Eeprom
Hybrid Technology Type:
Monolithic
Terminal Type And Quantity:
16 printed circuit
Purchase Description Identification:
4995-69-797-3811
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A450-0

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